# High-Current Overvoltage Protectors with Adjustable OVLO

#### **ABSOLUTE MAXIMUM RATINGS**

(All voltages referenced to GND.)	Continuous Power Dissipation ( $T_A = +70$ °C)
IN0.3V to +40V	TDFN (derate 11.9mW/°C above +70°C)954mW
OUT0.3V to (V <sub>IN</sub> + 0.3V)	Operating Temperature Range40°C to +85°C
OVLO0.3V to +6V	Junction Temperature+150°C
Continuous IN, OUT Current (Note 1)3A	Storage Temperature Range65°C to +150°C
Peak IN, OUT Current (10ms)5A	Lead Temperature (soldering, 10s)+300°C
Continuous OVLO Current50µA	Soldering Temperature (reflow)+260°C

Note 1: Continuous current limited by thermal design.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **PACKAGE THERMAL CHARACTERISTICS (Note 2)**

TDFN

Junction-to-Ambient Thermal Resistance ( $\theta_{JA}$ )......83.9°C/W Junction-to-Case Thermal Resistance ( $\theta_{JC}$ ).............37°C/W

**Note 2:** Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <a href="https://www.maxim-ic.com/thermal-tutorial">www.maxim-ic.com/thermal-tutorial</a>.

#### **ELECTRICAL CHARACTERISTICS\***

 $(V_{IN} = +2.2V \text{ to } +36V, T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$  Typical values are at  $V_{IN} = +5.0V \text{ and } T_A = +25^{\circ}\text{C}.)$  (Note 3)

PARAMETER	SYMBOL	cc	ONDITIONS	MIN	TYP	MAX	UNITS
Input Voltage Range	V <sub>IN</sub>			2.2		36	V
Input Supply Current	I <sub>IN</sub>	V <sub>IN</sub> < 5V			65	120	μΑ
		V. riging	MAX14586	6.8	7	7.2	
Input Supply Current  IN Overvoltage Trip Level  IN Overvoltage Lockout Hysteresis  OVLO Set Threshold Adjustable OVLO Threshold Range  External OVLO Select Threshold  Switch On-Resistance	\/	V <sub>IN</sub> rising	MAX14590	14.5	15	15.5	V
	V <sub>IN_OVLO</sub>	V folling	MAX14586	6.73	6.93	7.13	V
		V <sub>IN</sub> falling	MAX14590	14.35	14.85	15.35	
l .	V <sub>IN_OVLO_HYS</sub>				1		%
OVLO Set Threshold	V <sub>OVLO_THRESH</sub>			1.18	1.223	1.26	V
-				4		20	V
	Vovlo_select			0.25	0.35	0.4	V
Cuitab On Decistance	В	I <sub>OUT</sub> = 100mA, T	$T_A = +25^{\circ}C, V_{IN} = 5V$		48	81	O
SWILCH OH-NESISTATICE	R <sub>ON</sub>	$I_{OUT} = 100$ mA, T	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			115	mΩ
OVLO Clamp		$I_{CLAMP} = 10\mu A,$	$V_{IN} = 5V$		3.6		V
OUT Capacitor	C <sub>OUT</sub>					1000	μF
OVLO Input Leakage Current	I <sub>OVLO</sub>	V <sub>OVLO_THRESH</sub> =	= 1.221V	-100		+100	nA
Thermal Shutdown					+150		°C
Thermal Shutdown Hysteresis					20		°C

Maxim Integrated Products 2

<sup>\*</sup>The parametric values (min, typ, max limits) shown in the Electrical Characteristics table supersede values quoted elsewhere in this data sheet.

# High-Current Overvoltage Protectors with Adjustable OVLO

#### **ELECTRICAL CHARACTERISTICS\* (continued)**

 $(V_{IN} = +2.2V \text{ to } +36V, T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$  Typical values are at  $V_{IN} = +5.0V \text{ and } T_A = +25^{\circ}\text{C}.)$  (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
TIMING CHARACTERISTICS (Figure 1)						
Debounce Time	ince Time $ t_{\text{INDBC}} \qquad                                  $		15		ms	
Soft-Start Time	t <sub>SS</sub>	Soft-start time beginning from V <sub>OUT</sub> = 10% of V <sub>IN</sub> to soft-start off		15		ms
Switch Turn-On Time	+	$ \begin{array}{c} 2.2V < V_{IN} < V_{IN\_OVLO},  R_{LOAD} = 100\Omega, \\ C_{LOAD} = 100\mu F;  V_{OUT}  from  10\%  to  90\% \\ of  V_{IN} \end{array} $		1.48		mo
Switch fulli-Oil fillie	<sup>†</sup> ON	$ \begin{array}{c} 2.2 \text{V} < \text{V}_{\text{IN}} < \text{V}_{\text{IN\_OVLO}},  \text{R}_{\text{LOAD}} = 100 \Omega, \\ \text{C}_{\text{LOAD}} = 1 \text{mF};  \text{V}_{\text{OUT}}  \text{from 10\% to 90\%} \\ \text{of V}_{\text{IN}} \end{array} $		5.24		ms
Switch Turn-Off Time	tOFF	$V_{IN}$ > $V_{OVLO\_THRESH}$ to $V_{OUT}$ = 80% of $V_{IN\_OVLO}$ ; $R_{LOAD}$ = 100 $\Omega$ , $V_{IN}$ rising at 2V/ $\mu$ s		0.8	3.5	μs

Note 3: All specifications are 100% production tested at T<sub>A</sub> = +25°C, unless otherwise noted. Specifications are over -40°C to +85°C and are guaranteed by design.

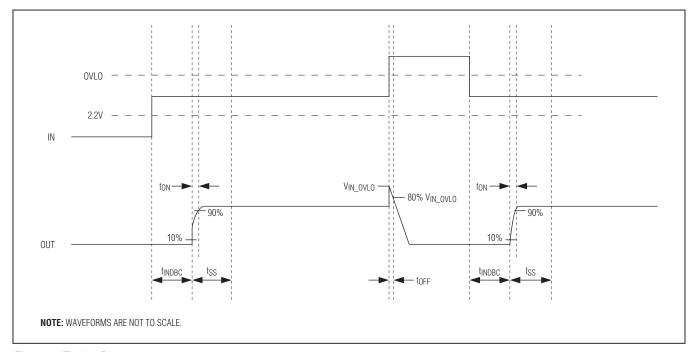


Figure 1. Timing Diagram

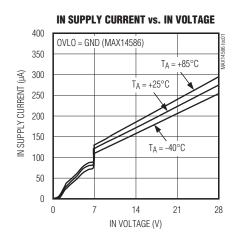
Maxim Integrated Products 3

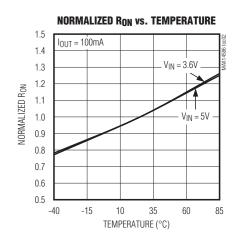
<sup>\*</sup>The parametric values (min, typ, max limits) shown in the Electrical Characteristics table supersede values quoted elsewhere in this data sheet.

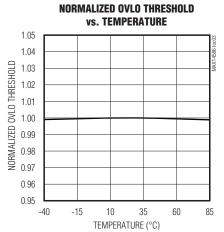
# **High-Current Overvoltage Protectors** with Adjustable OVLO

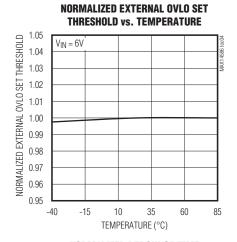
## **Typical Operating Characteristics**

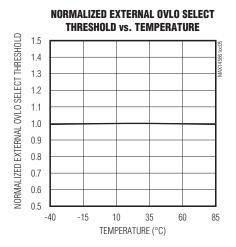
 $(V_{IN} = +5.0V, C_{IN} = 1\mu F, C_{OUT} = 1\mu F, T_A = +25^{\circ}C, unless otherwise noted.)$ 

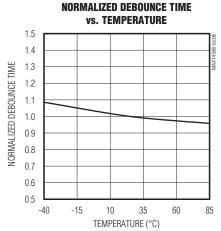








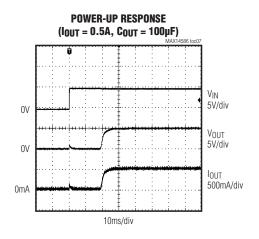


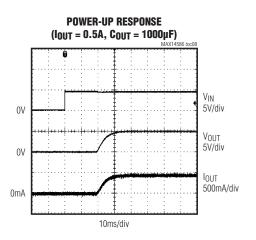


# **High-Current Overvoltage Protectors** with Adjustable OVLO

### **Typical Operating Characteristics (continued)**

(V<sub>IN</sub> = +5.0V, C<sub>IN</sub> = 1 $\mu$ F, C<sub>OUT</sub> = 1 $\mu$ F, T<sub>A</sub> = +25°C, unless otherwise noted.)

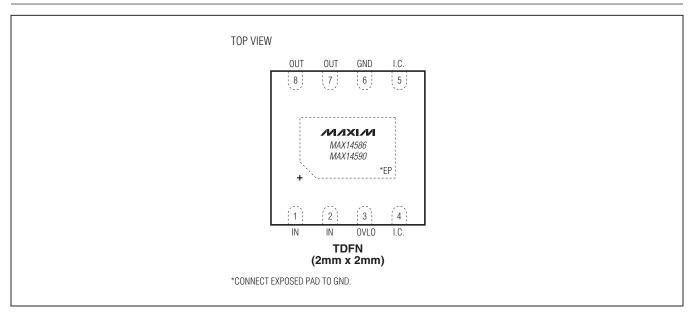




# **OVERVOLTAGE FAULT RESPONSE** $(I_{OUT} = 0.5A, C_{OUT} = 100\mu F)$ 0V 5V/div 0V $V_{OUT}$ 0mA 500mA/div 10µs/div

# **High-Current Overvoltage Protectors** with Adjustable OVLO

## **Pin Configuration**

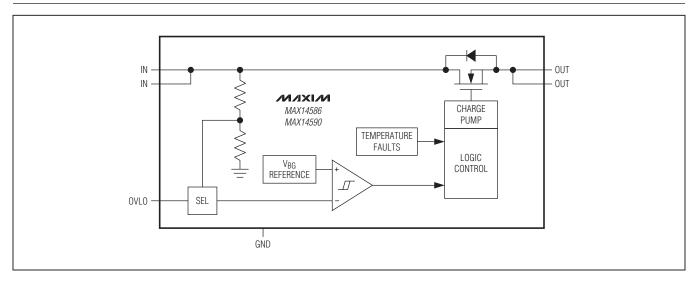


# **Pin Description**

PIN	NAME	FUNCTION		
1, 2	Voltage Input. Bypass IN with a 1µF ceramic capacitor as close as possible to the device to ±15kV Human Body Model (HBM) ESD protection. Connect both IN pins together for proper is protected to ±2kV HBM when IN is not bypassed with a capacitor to GND.			
3	OVLO  External OVLO Adjustment. Connect OVLO to GND when using the internal threshold. Connect a r divider to OVLO to set a different OVLO threshold; this external resistor-divider is completely indep from the internal threshold.			
4, 5	I.C.	Internally Connected. Connect I.C. to GND or leave I.C. unconnected.		
6 GND Ground 7, 8 OUT Output Voltage. Output of internal switch. Connect both OUT pins together for proper		Ground		
		Output Voltage. Output of internal switch. Connect both OUT pins together for proper operation.		
_	EP	Exposed Pad. Connect EP to ground. For enhanced thermal dissipation, connect EP to a copper area as large as possible. Do not use EP as the only ground connection.		

# **High-Current Overvoltage Protectors** with Adjustable OVLO

#### **Functional Diagram**



#### **Detailed Description**

The MAX14586/MAX14590 overvoltage protection devices feature a low on-resistance (RON) internal FET and protect low-voltage systems against voltage faults up to +36V. If the input voltage exceeds the overvoltage threshold, the internal FET is turned off to prevent damage to the protected components. The 15ms debounce time prevents false turn-on of the internal FET during startup.

#### **Device Operation**

The devices have timing logic that controls the turn-on of the internal FET. If  $V_{IN} < V_{OVLO\ THRESH}$ , the internal charge pump is enabled. The charge-pump startup, after a 15ms debounce delay, turns on the internal FET (see the Functional Diagram). After the debounce time, softstart limits the FET inrush current for 15ms (typ). At any time, if VIN rises above VOVI O THRESH, OUT is disconnected from IN.

#### **Internal Switch**

The devices incorporate an internal FET with a  $48m\Omega$ (typ) RON. The FET is internally driven by a charge pump that generates a necessary gate voltage above IN. The internal FET can pass more than 5A inrush current.

#### **Overvoltage Lockout (OVLO)**

The MAX14586 has a 7V (typ) overvoltage threshold. The MAX14590 has a 15V (typ) overvoltage threshold.

#### **Thermal Shutdown Protection**

The devices feature thermal shutdown circuitry. The internal FET turns off when the junction temperature exceeds +150°C (typ). The device exits thermal shutdown after the junction temperature cools by 20°C (typ).

### **Applications Information**

#### **IN Bypass Capacitor**

For most applications, bypass IN to GND with a 1µF ceramic capacitor as close as possible to the device to enable ±15kV (HBM) ESD protection on IN. If ±15kV (HBM) ESD is not required, there is no capacitor required at IN. If the power source has significant inductance due to long lead length, take care to prevent overshoots due to the LC tank circuit and provide protection if necessary to prevent exceeding the +40V absolute maximum rating on IN.

#### **OUT Output Capacitor**

The slow turn-on time provides a soft-start function that allows the devices to charge an output capacitor up to 1000µF without turning off due to an overcurrent condition.

# **High-Current Overvoltage Protectors** with Adjustable OVLO

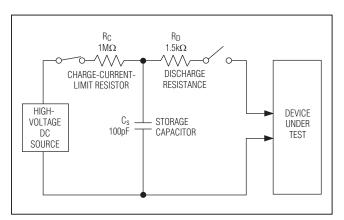


Figure 2a. Human Body ESD Test Model

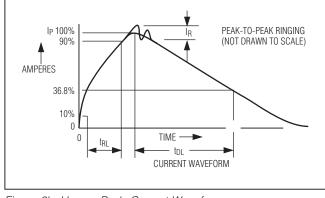


Figure 2b. Human Body Current Waveform

#### **External OVLO Adjustment Functionality**

If OVLO is connected to ground, the internal OVLO comparator uses the internally set OVLO value.

If an external resistor-divider is connected to OVLO and V<sub>OVI</sub> O exceeds the OVLO select voltage (V<sub>OVLO</sub> SELECT). the internal OVLO comparator reads the IN fraction fixed by the external resistor-divider.

 $R1 = 1M\Omega$  is a good starting value for minimum current consumption. Since VIN OVLO, VOVLO THRESH, and R1 are known, R2 can be calculated from the following formula:

$$V_{IN\_OVLO} = V_{OVLO\_THRESH} \times \left[1 + \frac{R1}{R2}\right]$$

This external resistor-divider is completely independent from the internal resistor-divider.

#### **ESD Test Conditions**

ESD performance depends on a number of conditions.

The devices are specified for ±15kV (HBM) typical ESD resistance on IN when IN is bypassed to ground with a 1µF ceramic capacitor.

#### **Human Body Model ESD Protection**

Figure 2a shows the HBM and Figure 2b shows the current waveform it generates when discharged into a low-impedance state. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the device through a  $1.5k\Omega$  resistor.

#### Ordering Information/ **Selector Guide**

PART	PIN-PACKAGE	TOP MARK	OVLO (V)
<b>MAX14586</b> ETA+T	8 TDFN-EP*	BNJ	7
MAX14590ETA+T	8 TDFN-EP*	BNK	15

Note: All devices are specified over the -40°C to +85°C operating temperature range.

+Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

\*EP = Exposed pad.

## **Chip Information**

PROCESS: BiCMOS

## **Package Information**

For the latest package outline information and land patterns (footprints), go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN NO.
8 TDFN-EP	T822+2	<u>21-0168</u>	

# High-Current Overvoltage Protectors with Adjustable OVLO

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	3/11	Initial release	_

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.